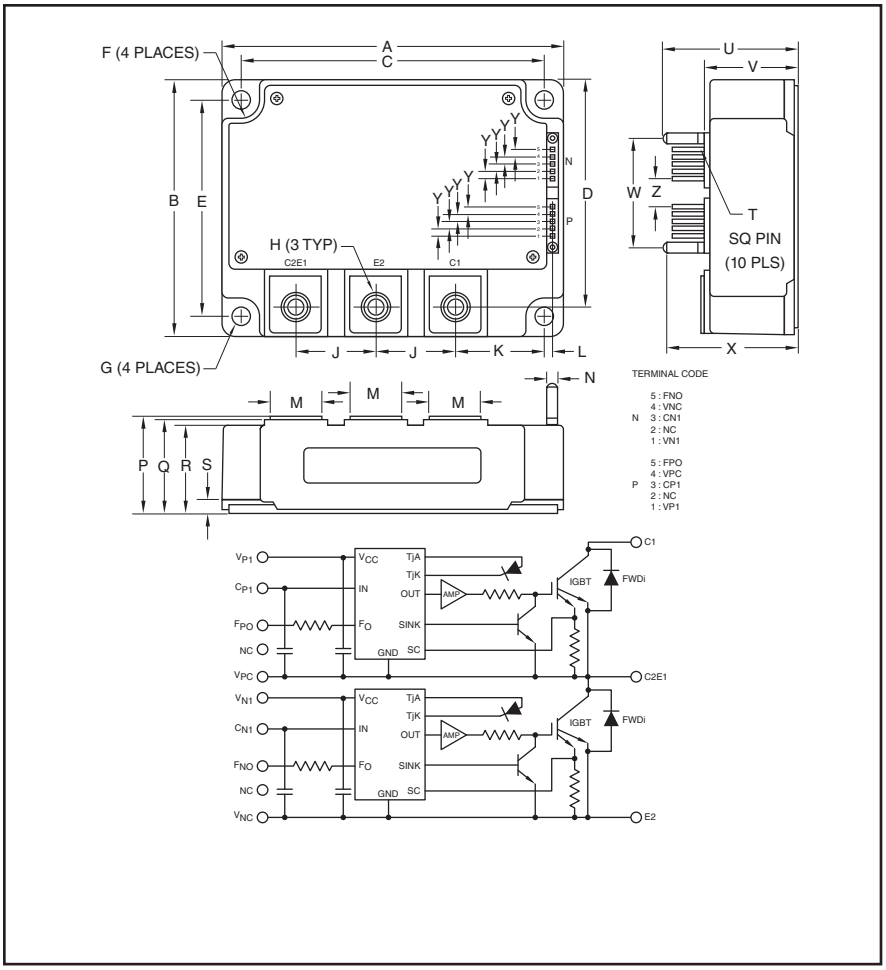
PM800DV1B060

Powerex, Inc., 173 Pavilion Lane, Youngwood, Pennsylvania 15697 (724) 925-7272
www.pwrx.com

Intellimod™ Module

Single Phase
IGBT Inverter Output
800 Amperes/600 Volts



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	4.72	120.0
B	3.54	90.0
C	4.17±0.010	106.0±0.25
D	2.87	73.0
E	2.99±0.010	76.0±0.25
F	0.26 Rad.	6.5 Rad.
G	0.26 Dia.	6.5 Dia.
H	M8 Metric	M8
J	1.10	28.0
K	1.22	31.0
L	0.12±0.02	3.0±0.5
M	0.71	18.0

Dimensions	Inches	Millimeters
N	0.14 Dia.	3.5 Dia.
P	1.34+0.04/-0.02	34.0+1.0/-0.5
Q	1.29	32.8
R	1.22	31.0
S	0.16	4.0
T	0.025 Sq.	0.64 Sq.
U	1.79	45.5
V	1.34	34.0
W	1.52	38.5
X	1.73	44.0
Y	0.10	2.54
Z	0.40	10.16



Description:
Powerex Intellimod™ Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:
- ☐ Complete Output Power Circuit
- ☐ Gate Drive Circuit
- ☐ Protection Logic
  - – Short Circuit
  - – Over Temperature
  - – Under Voltage

Applications:
- ☐ Inverters
- ☐ UPS
- ☐ Motion/Servo Control
- ☐ Power Supplies

Ordering Information:
Example: Select the complete part number from the table below -i.e. PM800DV1B060 is a 600V, 800 Ampere Intellimod™ Intelligent Power Module.

Type	Current Rating Amperes	V_{CES} Volts (x 10)
PM	800	60

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Absolute Maximum Ratings, T_j = 25°C unless otherwise specified

Characteristics	Symbol	PM800DV1B060	Units
Power Device Junction Temperature	T_j	-20 to 150	°C
Storage Temperature	T_{stg}	-40 to 125	°C
Case Operating Temperature	T_C	-20 to 100	°C
Mounting Torque, M6 Mounting Screws (Typical)	M_s	43	in-lb
Mounting Torque, M8 Main Terminal Screws (Typical)	M_t	87	in-lb
Module Weight (Typical)	m	720	Grams
Supply Voltage Protected by SC (V_D = 13.5 ~16.5V, Inverter Part, T_j = 125°C Start)	$V_{CC(prot)}$	400	Volts
Surge Supply Voltage (Applied between C1-E2, Surge Value)	$V_{CC(surge)}$	500	Volts
Isolation Voltage, (60Hz, Sinusoidal, Charged Part to Base, AC 1 minute)	V_{RMS}	2500	Volts

Inverter Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	600	Volts
Collector Current (T_C = 25°C)	I_C	800	Amperes
Peak Collector Current (Pulse)	I_{CRM}	1600	Amperes
Emitter Current (T_C = 25°C)	I_E	800	Amperes
Peak Emitter Current (Pulse)	I_{ERM}	1600	Amperes
Total Power Dissipation (T_C = 25°C)*1	P_{tot}	2500	Watts

Control Sector

Supply Voltage (Applied Between V_{P1}-V_{PC}, V_{N1}-V_{NC})	V_D	20	Volts
Input Voltage (Applied Between C_{P1}-V_{PC}, V_{N1}-V_{NC})	V_{CIN}	20	Volts
Fault Output Supply Voltage (Applied Between F_{PO}-V_{PC}, F_{NO}-V_{NC})	V_{FO}	20	Volts
Fault Output Current (Sink Current at F_{PO}, F_{NO} Terminals)	I_{FO}	20	mA

*1 Case temperature (T_C) measured point is just under the chips.

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 800A, Pulsed, T_j = 25°C	—	1.85	2.35	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 800A, Pulsed, T_j = 125°C	—	1.85	2.35	Volts
Emitter-Collector Voltage	V_{EC}	I_E = 800A, V_D = 15V, V_{CIN} = 15V	—	1.7	2.8	Volts
Switching Times	t_{on}	V_D = 15V, V_{CIN} = 0 ~ 15V,	0.3	0.8	2.0	µs
	t_{rr}	V_{CC} = 300V, I_C = 800A,	—	0.25	0.8	µs
	$t_{C(on)}$	T_j = 125°C,	—	0.4	1.0	µs
	t_{off}	Inductive Load	—	1.4	2.3	µs
	$t_{C(off)}$	(Per 1 Arm)	—	0.3	1.0	µs
Collector-Emitter Cutoff Current	I_{CES}	V_{CE} = V_{CES}, V_D = 15V, V_{CIN} = 15, T_j = 25°C	—	—	1.0	mA
		V_{CE} = V_{CES}, V_D = 15V, V_{CIN} = 15, T_j = 125°C	—	—	10.0	mA
Control Sector						
Circuit Current	I_D	V_D = 15V, V_{CIN} = 15V, V_{P1}-V_{PC}	—	2	4	mA
		V_D = 15V, V_{CIN} = 15V, V_{N1}-V_{NC}	—	2	4	mA
Input ON Threshold Voltage	$V_{th(on)}$	Applied Between	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{th(off)}$	C_{P1}-V_{PC}, C_{N1}-V_{NC}	1.7	2.0	2.3	Volts
Short Circuit Trip Level	SC	-20°C ≤ T_j ≤ 125°C, V_D = 15V	1200	—	—	Amperes
Short Circuit Current Delay Time	$t_{off(SC)}$	V_D = 15V	—	0.2	—	µs
Over Temperature Protection	OT	Trip Level	135	—	—	°C
(Detect Temperature of Chip)	$OT_{(hys)}$	Reset Level	—	20	—	°C
Supply Circuit Under Voltage Protection	UV_t	Trip Level	11.5	12.0	12.5	Volts
(-20°C ≤ T_j ≤ 125°C)	UV_r	Reset Level	—	12.5	—	Volts
Fault Output Current	$I_{FO(H)}$	V_D = 15V, V_{FO} = 15V*2	—	—	0.01	mA
	$I_{FO(L)}$	V_D = 15V, V_{FO} = 15V*2	—	10	15	mA
Fault Output Pulse Width	t_{FO}	V_D = 15V*2	1.0	1.8	—	ms

*2 Fault output is given only when the internal SC, OT and UV protection.
Fault output of SC, OT and UV protection operate by lower arms.
Fault output of SC protecton given pulse.
Fault output of OT, UV protection given pulse while over trip level.

Thermal Characteristics

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{th(j-c)Q}$	Inverter IGBT (Per 1 Element)*1	—	—	0.05	K/Watt
	$R_{th(j-c)D}$	Inverter FWDi (Per 1 Element)*1	—	—	0.09	K/Watt
Contact Thermal Resistance	$R_{th(c-s)}$	Case to Heatsink (Per 1 Module), Thermal Grease Applied*1	—	0.014	—	K/Watt

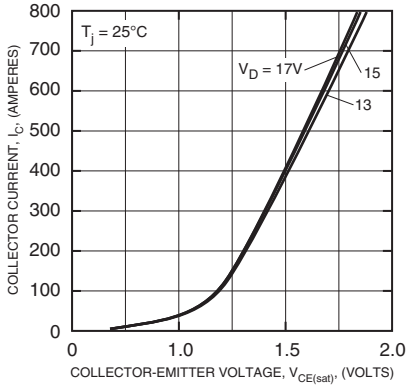
Recommended Conditions for Use

Characteristic	Symbol	Condition	Value	Units
Supply Voltage	V_{CC}	Applied Across C1-E2 Terminals	≤ 400	Volts
Control Supply Voltage	V_D	Applied Between V_{P1}-V_{PC}, V_{N1}-V_{NC}*3	15 ±1.5	Volts
Input ON Voltage	$V_{CIN(on)}$	Applied Between	≤ 0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$	C_{P1}-V_{PC}, C_{N1}-V_{NC}	≥ 4.0	Volts
PWM Input Frequency	f_{PWM}	Using Application Circuit	≤ 20	kHz
Arm Shoot-Through Blocking Time	t_{DEAD}	For IPM's each Input Signal	≥ 3.0	µs

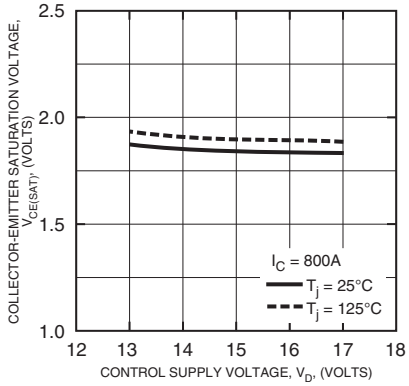
*1 Case temperature (T_C) measured point is just under the chips.
*3 With ripple satisfying the following conditions: dv/dt swing ≤ ±5V/µs, variation ≤ 2V peak to peak.

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Single Phase IGBT Inverter Output
800 Amperes/600 Volts

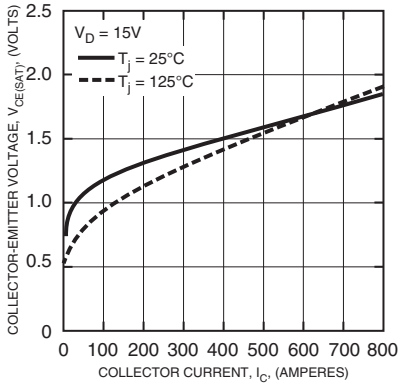
OUTPUT CHARACTERISTICS (TYPICAL)



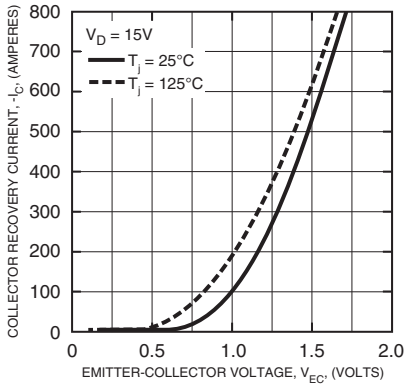
COLLECTOR-EMITTER SATURATON VOLTAGE CHARACTERISTICS (TYPICAL)



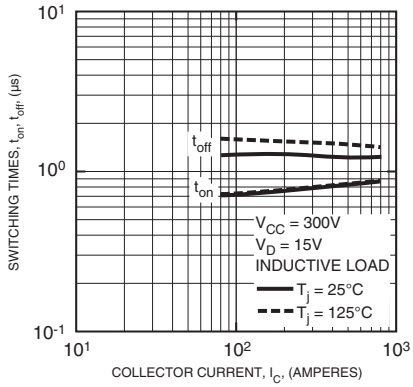
SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



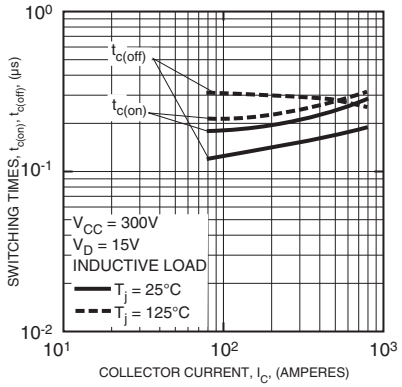
DIODE FORWARD CHARACTERISTICS (TYPICAL)



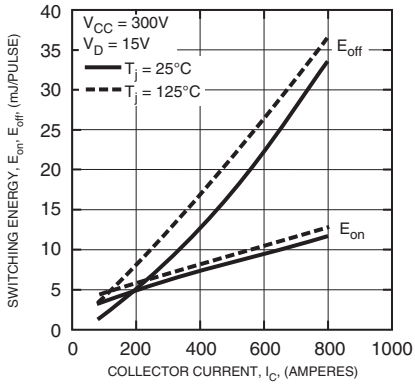
SWITCHING TIME VS. COLLECTOR CURRENT CHARACTERISTICS (TYPICAL)



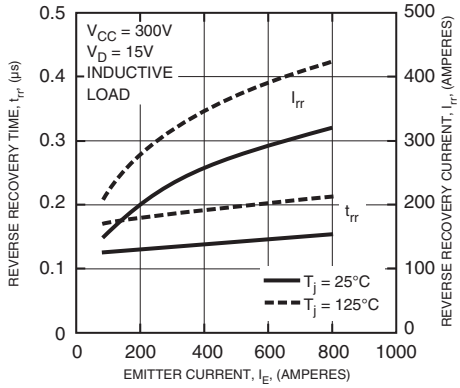
SWITCHING TIME VS. COLLECTOR CURRENT CHARACTERISTICS (TYPICAL)



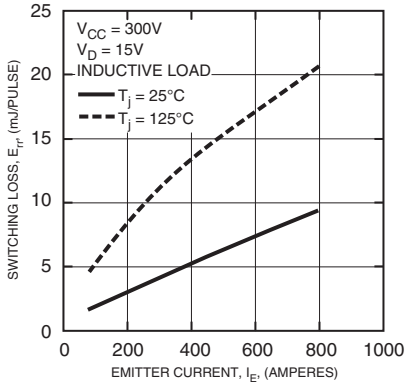
SWITCHING LOSS COLLECTOR CURRENT CHARACTERISTICS (TYPICAL)



REVERSE RECOVERY CHARACTERISTICS (TYPICAL)

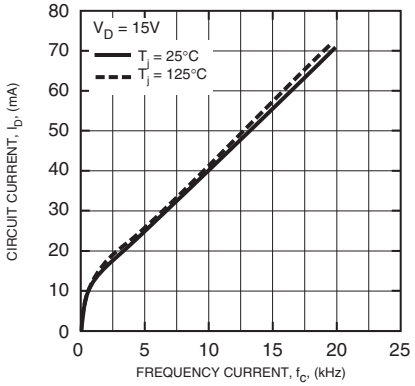


SWITCHING REVERSE RECOVERY LOSS CHARACTERISTICS (TYPICAL)

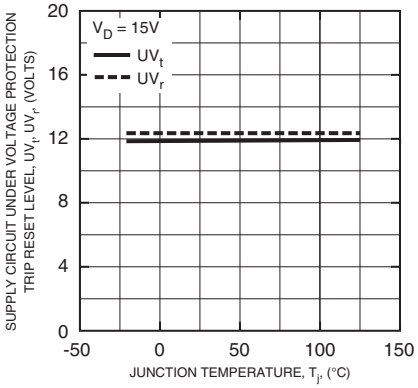


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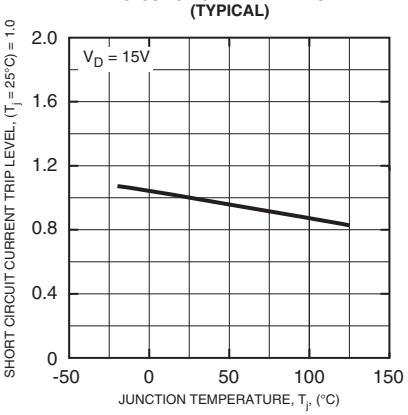
CIRCUIT CURRENT VS. FREQUENCY CURRENT (TYPICAL)



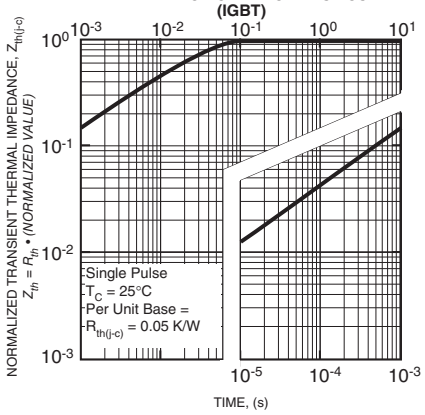
CONTROL SUPPLY VOLTAGE TRIP-RESET LEVEL TEMPERATURE DEPENDANCY (TYPICAL)



SHORT CIRCUIT TRIP LEVEL VS. JUNCTION TEMPERATURE (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (IGBT)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (FWDi)

